# **Dual Channel Small Outline Optoisolators** Transistor Output (Low Input Current)

The MOCD217 device consists of two gallium arsenide infrared emitting diodes optically coupled to two monolithic silicon phototransistor detectors, in a surface mountable, small outline, plastic package. It is ideally suited for high density applications and eliminates the need for through–the–board mounting.

- Dual Channel Coupler
- Convenient Plastic SOIC-8 Surface Mountable Package Style
- Low Input Current (Specified @ 1 mA)
- Minimum V(BR)CEO of 30 Volts Guaranteed
- Standard SOIC–8 Footprint, with 0.050" Lead Spacing
- Shipped in Tape and Reel, which conforms to EIA Standard RS481A
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input–Output Isolation of 3000 Vac (rms) Guaranteed
- Meets U.L. Regulatory Requirements, File #E54915

### **Ordering Information:**

- To obtain MOCD217 in tape and reel, add R2 suffix to device number as follows: R2 = 2500 units on 13" reel
- To obtain MOCD217 in quantities of 50 (shipped in sleeves) no suffix

### Marking Information:

MOCD217 = D217

### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit					
INPUT LED								
Forward Current — Continuous	١ <sub>F</sub>	60	mA					
Forward Current — Peak (PW = 100 µs, 120 pps)	I <sub>F</sub> (pk)	1.0	А					
Reverse Voltage	VR	6.0	V					
LED Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	90 0.8	mW mW/°C					
OUTPUT TRANSISTOR	-		-					
Collector–Emitter Voltage	VCEO	30	V					
Collector–Base Voltage	VCBO	70	V					
Emitter–Collector Voltage	VECO	7.0	V					
Collector Current — Continuous	IC	150	mA					
Detector Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	150 1.76	mW mW/°C					

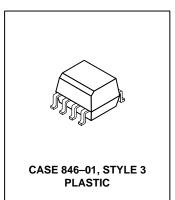
NOTE: Thickness through insulation between input and output is  $\geq 0.5$  mm.

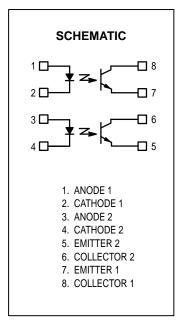


MOCD217

[CTR = 100% Min]

Motorola Preferred Device





Preferred devices are Motorola recommended choices for future use and best overall value.



## MOCD217

### **MAXIMUM RATINGS** — continued (T<sub>A</sub> = 25°C unless otherwise noted)

Rating			Symbol	Value		Unit
TOTAL DEVICE						
Input–Output Isolation Voltage <sup>(1,2)</sup> (60 Hz, 1.0 sec. duration)			VISO	3000		Vac(rms)
Total Device Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C			PD	250 2.94		mW mW/°C
Ambient Operating Temperature Range <sup>(3)</sup>			TA	-55 to +100		°C
Storage Temperature Range <sup>(3)</sup>			T <sub>stg</sub>	T <sub>stg</sub> -55 to +150		°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)			—	260		°C
ELECTRICAL CHARACTERISTI	<b>CS</b> (T <sub>A</sub> = 25°C unless otherwise	e noted)(4)				
Characteri	stic	Symbol	Min	<b>Typ</b> (4)	Max	Unit
NPUT LED			•			<b>I</b>
Forward Voltage (I <sub>F</sub> = 1.0 mA)		VF	—	1.05	1.3	V
Reverse Leakage Current (V <sub>R</sub> = 6.0 V)		IR		0.1	100	μΑ
Capacitance		С		18		pF
OUTPUT TRANSISTOR						
Collector-Emitter Dark Current	$(V_{CE} = 5.0 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C})$	ICEO1	_	1.0	50	nA
	$(V_{CE} = 5.0 \text{ V}, \text{ T}_{A} = 100^{\circ}\text{C})$	ICEO2	_	1.0	_	μΑ
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 100 µA)		V(BR)CEO	) 30	90		V
Emitter–Collector Breakdown Voltage (IE = 100 µA)		V(BR)ECO		7.8		V
Collector–Emitter Capacitance (f = $1.0 \text{ MHz}, V_{CE} = 0$ )		CCE		7.0	_	pF
COUPLED						
Output Collector Current ( $I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ )	MOCD217	I <sub>C</sub> (CTR) <sup>(5</sup>	) 1.0 (100)	1.3 (130)		mA (%)
Collector-Emitter Saturation Voltage	$(I_{C} = 100 \ \mu\text{A}, I_{F} = 1.0 \ \text{mA})$	VCE(sat)	_	0.35	0.4	V
Turn–On Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )		ton		7.5		μs
Turn–Off Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )		toff		5.7	_	μs
Rise Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )		tr		3.2	—	μs
Fall Time (I <sub>C</sub> = 2.0 mA, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 100 $\Omega$ )		t <sub>f</sub>		4.7		μs
Input–Output Isolation Voltage (f = 60 Hz, t = 1.0 sec.) <sup>(1,2)</sup>		VISO	3000	_		Vac(rms)
Isolation Resistance $(V_{I-O} = 500 \text{ V})^{(2)}$		RISO	10 <sup>11</sup>	_		Ω
Isolation Capacitance (V <sub>I-O</sub> = 0, f = 1.0 MHz) <sup>(2)</sup>		C <sub>ISO</sub>		0.2		pF

Input–Output Isolation Voltage, V<sub>ISO</sub>, is an internal device dielectric breakdown rating.
For this test, pins 1, 2, 3 and 4 are common, and pins 5, 6, 7 and 8 are common.
Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

4. Always design to the specified minimum/maximum electrical limits (where applicable).

5. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .

### **TYPICAL CHARACTERISTICS**

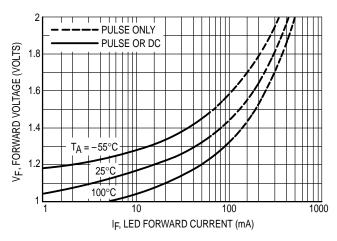


Figure 1. LED Forward Voltage versus Forward Current

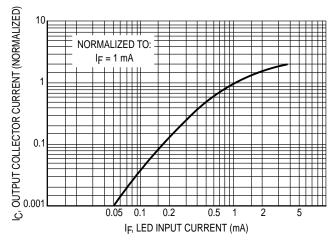


Figure 2. Output Current versus Input Current

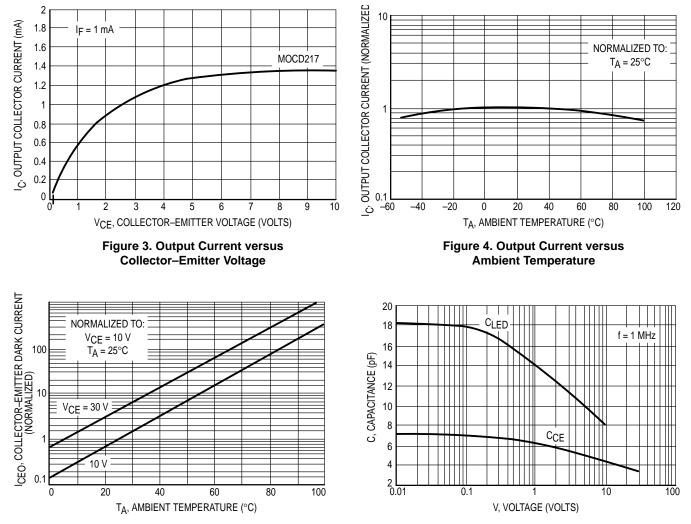
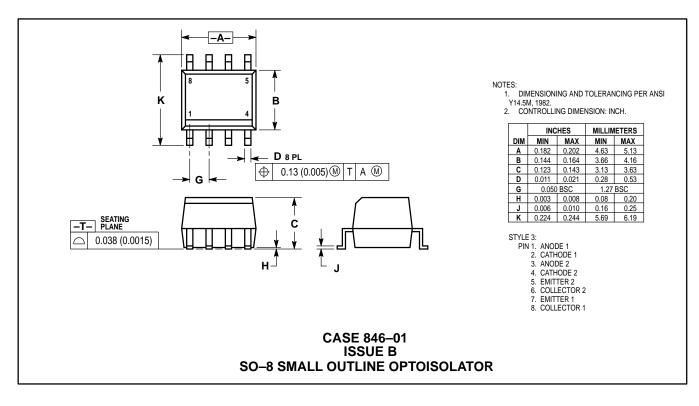


Figure 5. Dark Current versus Ambient Temperature

Figure 6. Capacitance versus Voltage

### PACKAGE DIMENSIONS



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